

/ Descriptions

TO-263

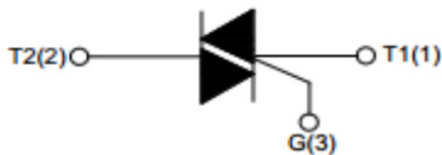
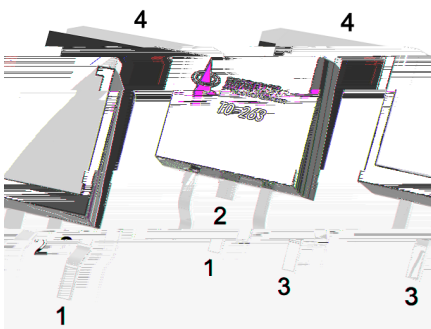
Triac in a TO-263 Plastic Package.

/ Features

Medium current triac, Low on state voltage drop, High reliability and stability, Low thermal resistance, HF Product.

/ Applications

Suitable for general purpose AC switching .Such as static relays, heating regulation, induction motor starting circuits, motor speed controllers, etc.

/ Equivalent Circuit**/ Pinning**

PIN1 Main Terminal 1 PIN 2 4 Main Terminal 2 PIN 3 Gate

/ Marking

See Marking Instructions.

/ Absolute Maximum Ratings($T_a=25^\circ\text{C}$)

Parameter	Symbol	Rating	Unit
Repetitive peak off-state/reverse voltages($T_j=125^\circ\text{C}$)	$V_{\text{DRM}}/V_{\text{RRM}}$	800	V
RMS on-state current($T_c=90^\circ\text{C}$)	$I_{\text{T(RMS)}}$	12	A
Non repetitive surge peak on-state current(full cycle, $T_j=25^\circ\text{C}$)	$I_{\text{TSM}(t=20\text{ms})}$	120	A
I^2t value for fusing($T_j=25^\circ\text{C}$)	$I^2t_{(tp=10\text{ms})}$	78	A^2s
Critical rate of rise of on-state current ($I_G=2I_{\text{GT}}$, $f=120\text{Hz}$ $T_j=125^\circ\text{C}$)	dI/dt I-II-III	50	A/ s
Peak gate current($t_p=20^\circ\text{s}$ $T_j=125^\circ\text{C}$)	I_{GM}	4.0	A
Average gate power dissipation($T_j=125^\circ\text{C}$)	$P_{\text{G(AV)}}$	1	W
Operating junction temperature range	T_j	-40 125	
Storage junction temperature range	T_{stg}	-40 150	
Junction to ambient(AC)	$R_{\text{th(j-a)}}$	60	/W
Junction to case for(AC)	$R_{\text{th(j-c)}}$	1.4	

/ Electrical Characteristics($T_j=25^\circ\text{C}$)

3 / Snubberless and logic level 3 quadrants)

Symbol	Test Conditions	Quadrant	Value		Unit
I_{GT}	$V_D=12\text{V}$ $R_L=30$	I-II-III	Max.	35	mA
V_{GT}	$V_D=12\text{V}$ $R_L=30$	I-II-III	Max.	1.3	V
V_{GD}	$V_D=V_{\text{DRM}}$ $R_L=3.3\text{K}$ $T_j=125$	I-II-III	Min.	0.2	V
I_L	$I_G=1.2I_{\text{GT}}$	I-III	Max.	50	mA
		II		60	
I_H	$I_T=100\text{mA}$		Max.	40	mA
(dV/dt)	$V_D=67\% V_{\text{DRM}}$ Gate Open	$T_j=125$	Min.	500	V/ s
V_{TM}	$I_{\text{TM}}=17\text{A}$ $t_p=380^\circ\text{s}$	$T_j=25$	Max.	1.55	V
I_{DRM}	$V_D=V_{\text{DRM}}$ $V_R=V_{\text{RRM}}$	$T_j=25$		5	A
I_{RRM}		$T_j=125$		1	mA

/ Electrical Characteristic Curve

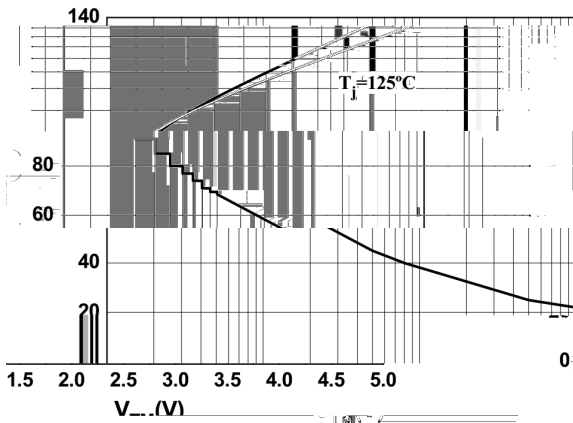
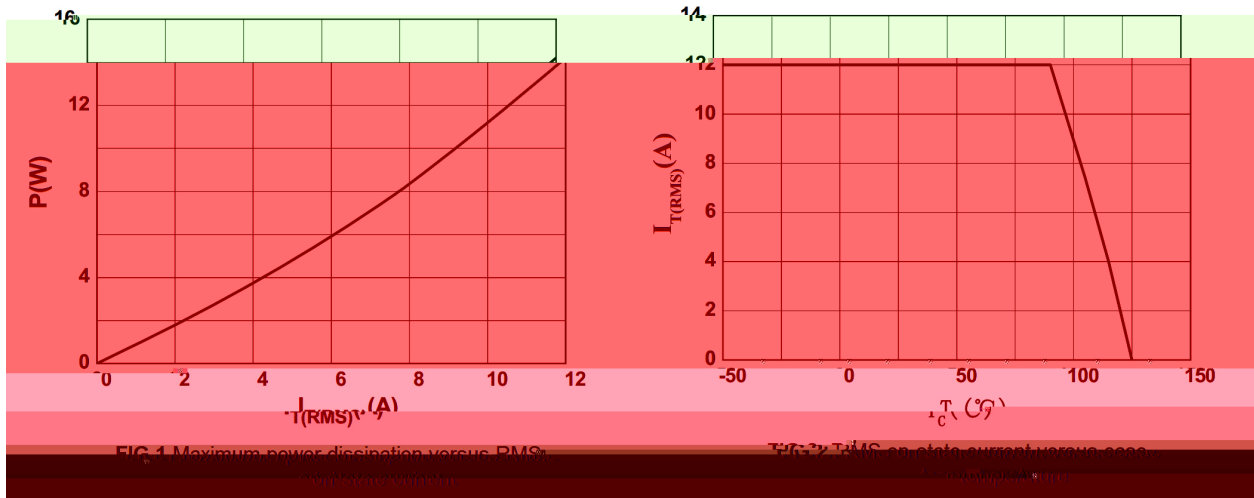


FIG.4: On-state characteristics

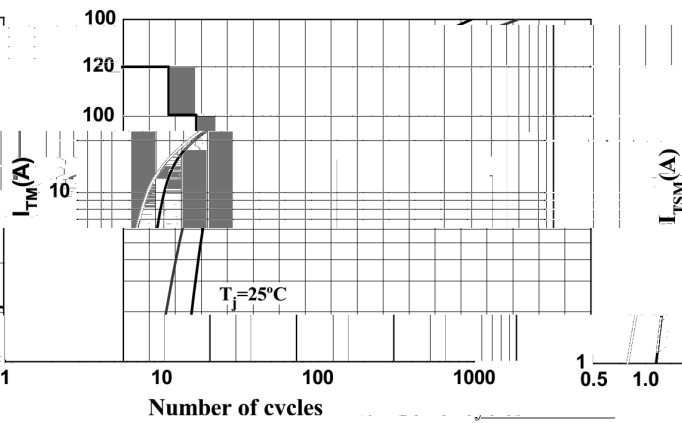


FIG.3: Surge peak on-state current versus number of cycles

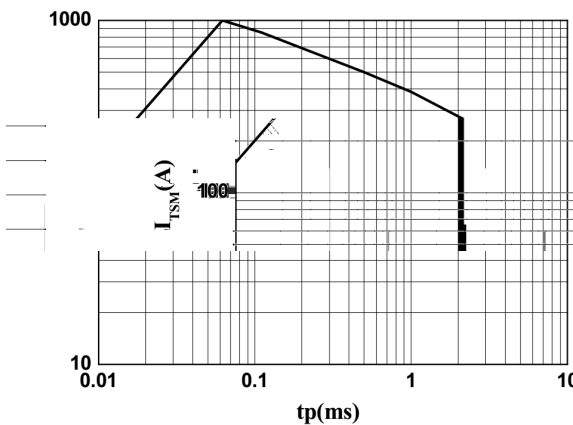
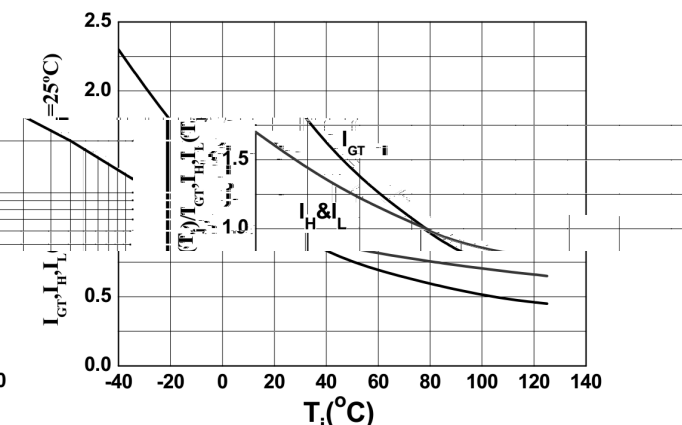


FIG. 5: Non repetitive surge peak on-state current

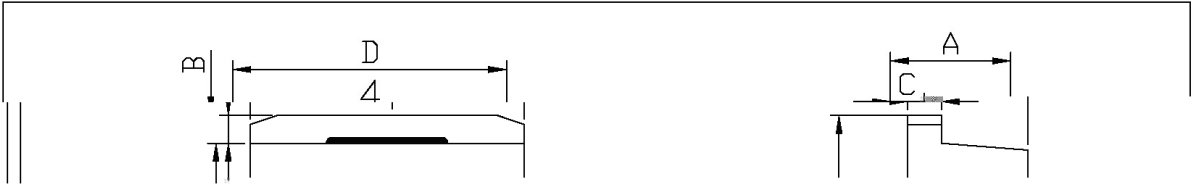


non repetitive surge peak on-state current and holding current at temperature

for a pulse width $tp < 10ms$, and corresponding value of I_{GT} ($dI/dt < 100A/\mu s$)

gate threshold voltage, holding current, and gate threshold voltage versus junction temperature

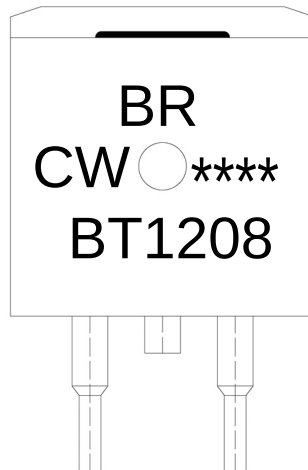
/ Package Dimensions



单位: mm						
Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters		
	Min	Max		Min	Max	
A	4.30	4.70	E _L	4.50	4.90	
B	1.00	1.40	e1	2.24	2.74	
b	0.70	0.90	e2	4.88	5.28	
b1	1.15	1.35	J1	15.00	16.00	
b2	0.40	0.60	L2	2.24	2.94	
C	1.20	1.40	L3	1.20	1.60	
D	9.80	10.20				

T1-252

/ Marking Instructions



BR

CW

I_{GT}

BT1208

Note:

BR: Company Code

CW: I_{GT} Bracket code

****: Lot No. Code, code change with Lot No

BT1208: Product Type Code

